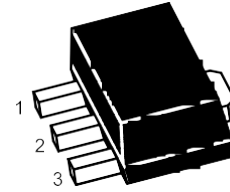


## NPN Silicon Epitaxial Planar Transistors

### Features

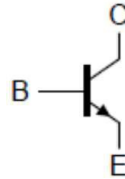
- AEC-Q101 Qualified
- Halogen and Antimony Free(HAF), RoHS compliant



1.Base 2.Collector 3.Emitter  
SOT-89 Plastic Package

### Mechanical Data

- SOT-89 Plastic Package
- Mounting position: Any



Absolute Maximum Ratings (T <sub>A</sub> =25°C unless otherwise noted)			
Parameter	Symbol	Value	Unit
Collector Base Voltage	V <sub>CBO</sub>	100	V
Collector Emitter Voltage	V <sub>CEO</sub>	80	V
Emitter Base Voltage	V <sub>EBO</sub>	5	V
Collector Current	I <sub>C</sub>	1	A
Peak Collector Current	I <sub>CM</sub>	1.5	A
Total Power Dissipation	P <sub>tot</sub>	0.5 <sup>1)</sup> 1.3 <sup>2)</sup>	W
Junction Temperature	T <sub>j</sub>	150	°C
Storage Temperature Range	T <sub>stg</sub>	- 65 to + 150	°C

Thermal Characteristics			
Parameter	Symbol	Value	Unit
Thermal Resistance Junction to Ambient <sup>1)</sup>	R <sub>thJA</sub>	250 <sup>1)</sup> 94 <sup>2)</sup>	°C/W

<sup>1)</sup> Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.

<sup>2)</sup> Device mounted on FR-4 substrate PC board, 2oz copper, with 1-inch square copper plate.

Electrical Characteristics (T <sub>A</sub> = 25°C unless otherwise noted)					
Parameter	Symbol	Min.	Typ.	Max.	Unit
DC Current Gain at V <sub>CE</sub> = 2 V, I <sub>C</sub> = 5 mA at V <sub>CE</sub> = 2 V, I <sub>C</sub> = 500 mA at V <sub>CE</sub> = 2 V, I <sub>C</sub> = 150 mA ABCX56-10U ABCX56-16U	h <sub>FE</sub>	40 25 63 100	-	- - 160 250	-
Collector Base Cutoff Current at V <sub>CB</sub> = 30 V	I <sub>CBO</sub>	-	-	100	nA
Emitter Base Cutoff Current at V <sub>EB</sub> = 5 V	I <sub>EBO</sub>	-	-	100	nA
Collector Base Breakdown Voltage at I <sub>C</sub> = 100 μA	V <sub>(BR)CBO</sub>	100	-	-	V
Collector Emitter Breakdown Voltage at I <sub>C</sub> = 1 mA	V <sub>(BR)CEO</sub>	80	-	-	V
Emitter Base Breakdown Voltage at I <sub>E</sub> = 100 μA	V <sub>(BR)EBO</sub>	5	-	-	V
Collector Emitter Saturation Voltage at I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA	V <sub>CE(sat)</sub>	-	-	0.5	V
Base Emitter Saturation Voltage at I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA	V <sub>BE(sat)</sub>	-	-	1.2	V
Base Emitter Voltage at V <sub>CE</sub> = 2 V, I <sub>C</sub> = 500 mA	V <sub>BE</sub>	-	-	1	V
Transition Frequency at V <sub>CE</sub> = 5 V, I <sub>C</sub> = 50 mA, f = 100 MHz	f <sub>T</sub>	100	-	-	MHz
Collector Capacitance at V <sub>CB</sub> = 10 V, f = 1 MHz	C <sub>c</sub>	-	6	-	pF

## Typical Characteristics Curves

Fig. 1 Output Characteristics Curve

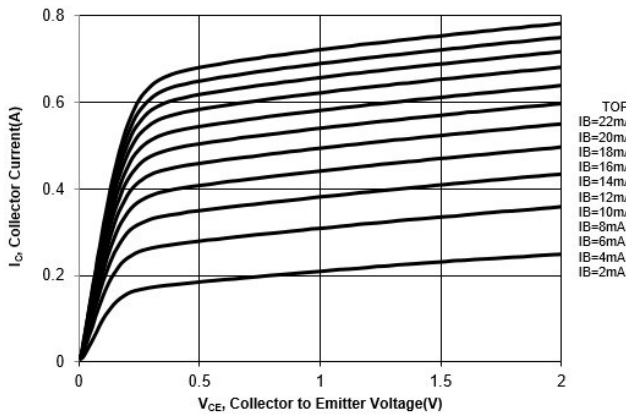


Fig. 2 Collector Current vs. Base to Emitter Voltage

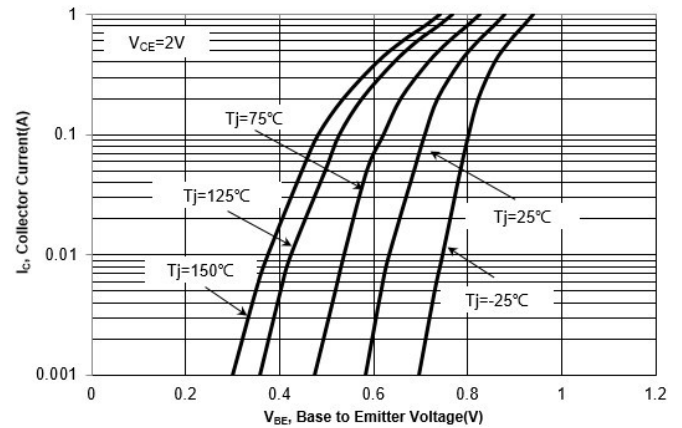


Fig. 3 DC Current Gain vs. Collector Current

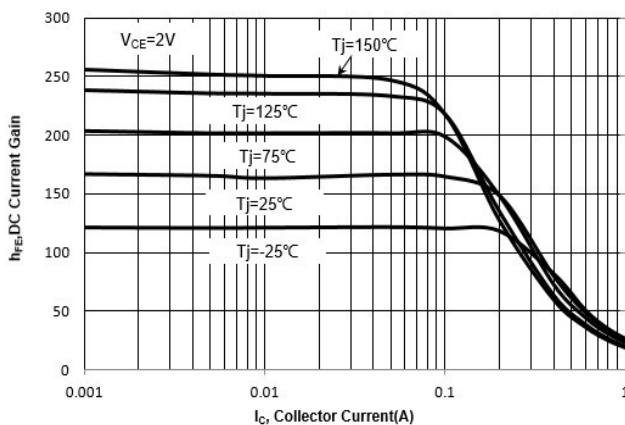


Fig. 4  $V_{BE(sat)}$  vs. Collector Current

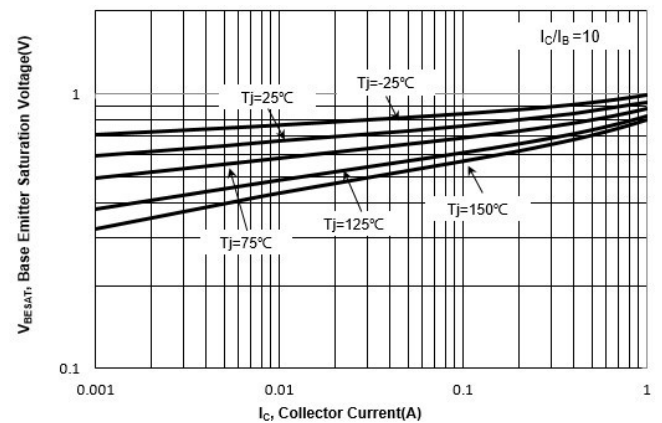


Fig. 5  $V_{CE(sat)}$  vs. Collector Current

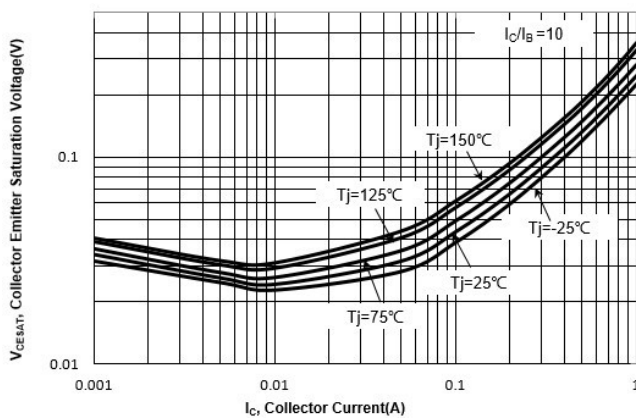


Fig. 6 Output Capacitance

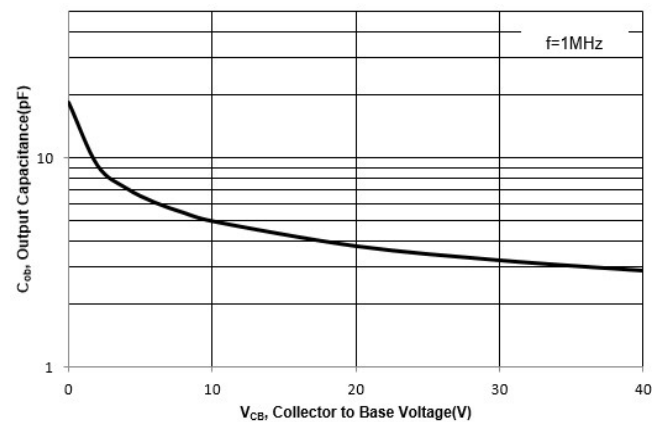
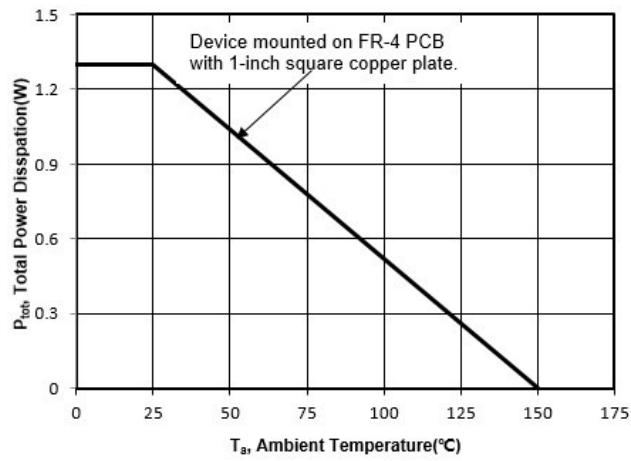
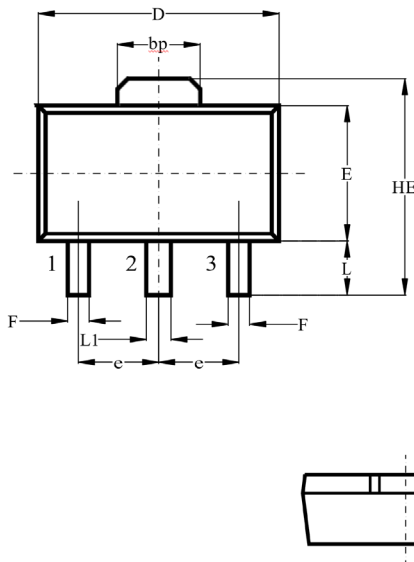


Fig. 7 Power Derating Curve



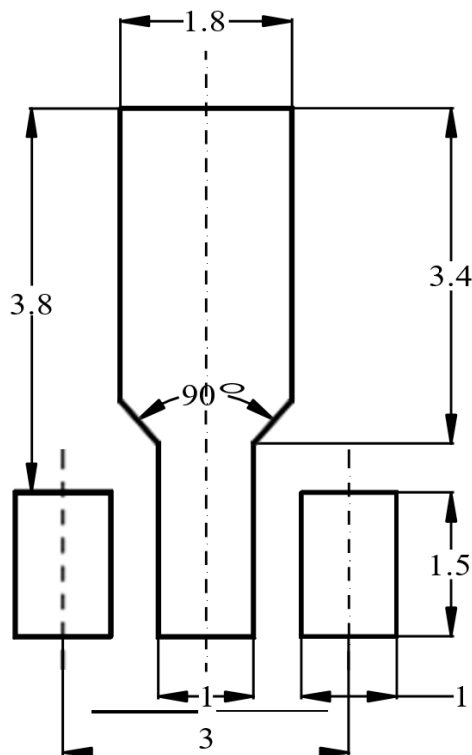
## Package Outline Dimensions (Unit: millimeters)

### SOT-89



SYMBOL	MILLIMETER		
	MIN	TYP	MAX
A	1.4	/	1.6
bp	1.5	/	1.6
C	0.3	/	0.5
D	4.4	/	4.6
E	2.4	/	2.6
F	0.35	/	0.45
HE	3.75	/	4.25
e	/	/	1.5
L	0.95	/	1.05
L1	0.41	/	0.51

## Recommended Soldering Footprint (Unit: millimeters)



## Packing Information

Package	Tape Width	Pitch		Reel Size		Per Reel Packing Quantity
	mm	mm	inch	mm	inch	
SOT-89	12	$8 \pm 0.1$	$0.315 \pm 0.004$	178	7	1000
				330	13	3000

## Revision History

Version	Date	Major Changes
Rev.A	2025.01.19	Official Release

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